

0.5Ω Ultra Low On-Resistance Dual SPDT Analog Switch UM5223 QFN10 1.8×1.4

General Description

The UM5223 is a low on-resistance ($R_{\rm ON}$), dual single-pole/double-throw (SPDT) analog switch operates from a single +1.65V to +4.5V supply. The device's targeted applications include battery powered equipment that benefit from its low on-resistance.

The UM5223 features two 0.5Ω R_{ON}(max) SPDT switches with 0.15Ω flatness and 0.05Ω matching between channels. The switch offers break-before-make switching (1ns) with t_{ON}<60ns and t_{OFF}<40ns at +2.7V.

The switch is available in Pb-free QFN10 package.

Applications

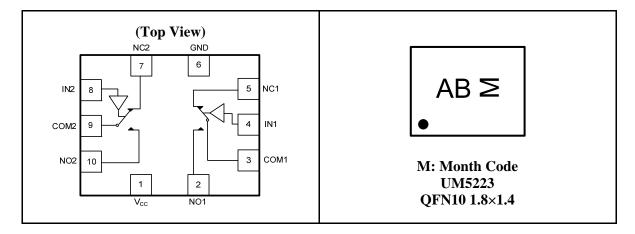
- Cell Phone Audio Block
- Speaker and Earphone Switching
- Portable Instrumentation
- Battery-Operated Equipment
- Modems
- Medical Equipment
- Computer Peripherals
- Ring-Tone Chip/Amplifier Switching

Features

- Ultra-Low $R_{ON} < 0.5\Omega$ at $V_{CC} = 3.0 \pm 0.3 V$
- R_{ON} Flatness of 0.15Ω
- Single-Supply Operation from +1.65V to +4.5V
- Interfaces with 2.8V Chipset
- Full 0-Vcc Signal Handing Capability
- Power Off Protection: When V_{CC}=0V, Input Signal can Tolerate up to 4.5V
- High Off-Isolation: -78dB (100kHz)
- Low Crosstalk: -92dB (100kHz)
- Low Distortion: 0.12%
- High Continuous Current Capability:
 ±300mA through Each Switch
- Lead (Pb)-Free QFN10 Package

Pin Configurations

Top View





Pin Description

Pin	Name	Function			
1	V_{CC}	Positive Supply Voltage			
2	NO1	Analog Switch 1-Normally Open Terminal			
3	COM1	Analog Switch 1-Common Terminal			
4	IN1	Analog Switch 1-Digital Control Input			
5	NC1	Analog Switch 1-Normally Closed Terminal			
6	GND	Ground Connection			
7	NC2	Analog Switch 2-Normally Closed Terminal			
8	IN2	Analog Switch 2-Digital Control Input			
9	COM2	Analog Switch 2-Common Terminal			
10	NO2	Analog Switch 2-Normally Open Terminal			

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty		
UM5223	QFN10 1.8×1.4	AB	3000pcs/7 Inch Tape & Reel		

Function Table

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

Absolute Maximum Ratings

Symbol	Parameter	Limit	Unit	
V_{+}	Supply Voltage	-0.3 to +5.5	V	
$V_{\rm S}$	DC Switch Voltage (Note 1)	-0.3 to $(V_{+}+0.3)$		
IN_	DC IN Voltage	-0.3 to +5.5		
Io	Continuous Current (COM_, NO_, NC_)	±300	т Л	
I_P	Peak Current (Pulsed at 1ms, 10% Duty Cycle)	±500	mA	
To	Operating Temperature Range	-40 to +85		
T_{J}	Junction Temperature	+150	°C	
T_{STG}	Storage Temperature Range	-65 to +150	C	
$T_{ m L}$	Junction Lead Temperature (Soldering, 10 Seconds)	+300		
ESD	ESD Method 3015.7	>2000	V	

Note 1: Signals on COM_, NO_, or NC_ exceeding V₊ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.



DC Electrical Characteristics

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40°C to 85°C)			Unit
	T ut utilicites	1 est conditions	, ((,)		Min	Тур	Max	CIII
I _{IN}	Input Leakage Current	V _{IN} =3.6V or GND	3.6	Room Full	-0.1 -1.0		0.1 1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} =3.6V or GND	0	Room Full	-0.5 -2.0		0.5 2.0	μΑ
I _{COM(ON)}	COM ON Leakage Current	$V_{IN}=V_{IL}$ or V_{IH} V_{NO} 0.3V or 3.3V with V_{NC} Floating or V_{NC} 0.3V or 3.3V with V_{NO} Floating $V_{COM}=0.3$ V or 3.3V	3.6	Room Full	-0.01 -0.1		0.01 0.1	μΑ
I _{NO/NC(OFF)}	OFF State Leakage Current	$V_{IN}=V_{IL}$ or V_{IH} V_{NO} or $V_{NC}=0.3V$ $V_{COM}=3.3V$	3.6	Room Full	-0.3		0.3	μΑ
I_{CC}	Quiescent Supply Current	Select V _{IS} =V _{CC} or GND	1.65 to 3.6	Room Full	-1.0 -2.0		1.0 2.0	μΑ
$ m V_{IH}$	Input High Voltage		3.0	Full	1.4			V
. 111			3.6		1.7			
$V_{ m IL}$	Input Low Voltage		3.0	Full			0.7	V
D	On-Resistance (Note 2)	$V_{IN}=V_{IL}$ or V_{IH} $V_{IS}=V_{CC}$ to GND $I_{COM}=100$ mA	3.0	Room Full		0.5 0.6		Ω
R_{ON}			3.6	Room Full		0.5 0.6		22
$\Delta R_{ m ON}$	On Resistance Match Between Channels	V_{IS} =1.5V I_{COM} =100mA;	3.0	Room Full			0.05 0.05	Ω
ΔN _{ON}	(Note 2,3,4)	V_{IS} =1.8V I_{COM} =100mA	3.6	Room Full			0.05 0.05	22
D	On Resistance Flatness	$V_{IS}=V_{CC}$ to GND	3.0	Room Full			0.15 0.15	Ω
$ m R_{FLAT}$	(Note 2,3,5)	$I_{COM}=100 \text{mA}$	3.6	Room Full			0.15 0.15	22

- Note 2: Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
- Note 3: Parameter is characterized but not tested in production.
- Note 4: $\Delta R_{ON} = R_{ON (B0)} R_{ON(B1)}$ measured at identical V_{CC} , temperature and voltage levels. Note 5: Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.



AC Electrical Characteristics

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40°C to 85°C)			Unit
Symbol	1 urumovor	Test Conditions	, cc (,)		Min	Тур	Max	
t _{ON}	Turn On Time	$V_{IS}=1.5V$ $R_L=50\Omega$, $C_L=35pF$	2.3 to 3.6	Room Full		50 60		ns
t_{OFF}	Turn Off Time	$V_{IS}=1.5V$ $R_L=50\Omega$, $C_L=35pF$	2.3 to 3.6	Room Full		30 40		ns
$t_{ m BBM}$	Break Before Make Time (Note 6)	V_{IS} =3.0V R_L =50 Ω , C_L =35pF	3.0	Room Full	2	15		ns
Q _{INJ}	Charge Injection (Note 6)	C_L =1.0nF, V_{GEN} =0V, R_{GEN} =0 Ω	1.65 to 3.6	Room		38		pC
$V_{\rm ISO}$	Off Isolation (Note 7)	C_L =5.0pF, f=100kHz	1.65 to 3.6	Room		-78		dB
VCT	Crosstalk	R_L =50 Ω , C_L =5.0pF, f=100kHz	1.65 to 3.6	Room		-92		dB
BW	-3dB Bandwidth		1.65 to 3.6	Room		75		MHz
THD	Total Harmonic Distortion (Note 6)	$\begin{array}{c} f_{IS}\text{=-}20\text{Hz to }20\text{kHz,} \\ R_L\text{=-}R_{GEN}\text{=-}600\Omega \\ C_L\text{=-}50\text{pF,} \\ V_{IS}\text{=-}2.0\text{V RMS} \end{array}$	3.0	Room		0.12		%
Capacita	Capacitance							
C_{IN}	IN Pin Input Capacitance (Note 8)	V _{CC} =3.6V				4.5		pF
C _{NO/NC}	NO/NC Port Off Capacitance (Note 8)	V _{CC} =3.6V				20		pF
C_{COM}	COM Port Capacitance when Switch is Enabled (Note 8)	V _{CC} =3.6V				55		pF

Note 6: Guaranteed by design.

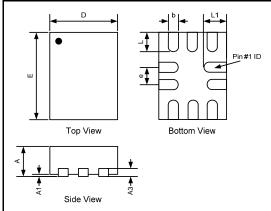
Note 7: Off Isolation=20 log10 [$V_{COM}/V_{NO/NC}$]. Note 8: T_A =+25°C, f=1MHz, Capacitance is characterized but not tested in production.



Package Information

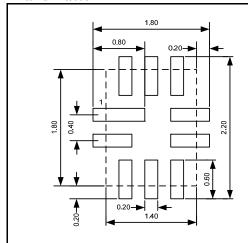
UM5223 QFN10 1.8×1.4

Outline Drawing



DIMENSIONS								
Camala al	MILLIMETERS			INCHES				
Symbol	Min	Тур	Max	Min	Тур	Max		
A	0.50	0.55	0.60	0.020	0.022	0.024		
A1	0.00	-	0.05	0.000	0.000 -			
A3	0.15REF			0.006REF				
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	1.35	1.40	1.45	0.053	0.055	0.057		
Е	1.75	1.80	1.85	0.069	0.071	0.073		
e	0.40BSC			0	.016BS0	\Box		
L	0.30	0.40	0.50	0.012	0.016	0.020		
L1	0.40	0.50	0.60	0.016	0.020	0.024		

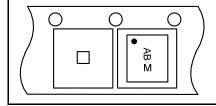
Land Pattern



NOTES:

- 1. Compound dimension: 1.80×1.40;
- 2. Unit: mm
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.

Tape and Reel Orientation





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